

RF AMPLIFIER

MODEL *TM6559*

Available as: TM6559, 4 Pin TO-8 (T4)
 TN6559, 4 Pin .450" Sq. Surface Mount (SM3)
 FP6559, 4 Pin Flatpack (FP4)
 BX6559, SMA Connectorized Housing (H1)

Features

- High Output Power: +22 dBm Typical
- Gain: 11.5 dB Typical
- Operating Temp. - 55 °C to +85 °C
- Environmental Screening Available

Specifications

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5-500 MHz	5-500 MHz
Gain (dB)	11.5	10 Min.
Power @ 1 dB Comp. (dBm)	22	20 Min.
Reverse Isolation (dB)	-15	-
VSWR In	1.5:1	2.0:1 Max.
Out	1.5:1	2.0:1 Max.
Noise figure (dB)	5.5	7.0 Max.
Power Vdc	+15	+15 Min.
mA	88	98 Max.

Note: Care should always be taken to effectively ground the case of each unit.

Revision 2-19-2024

Typical Intermodulation Performance at 25 ° C

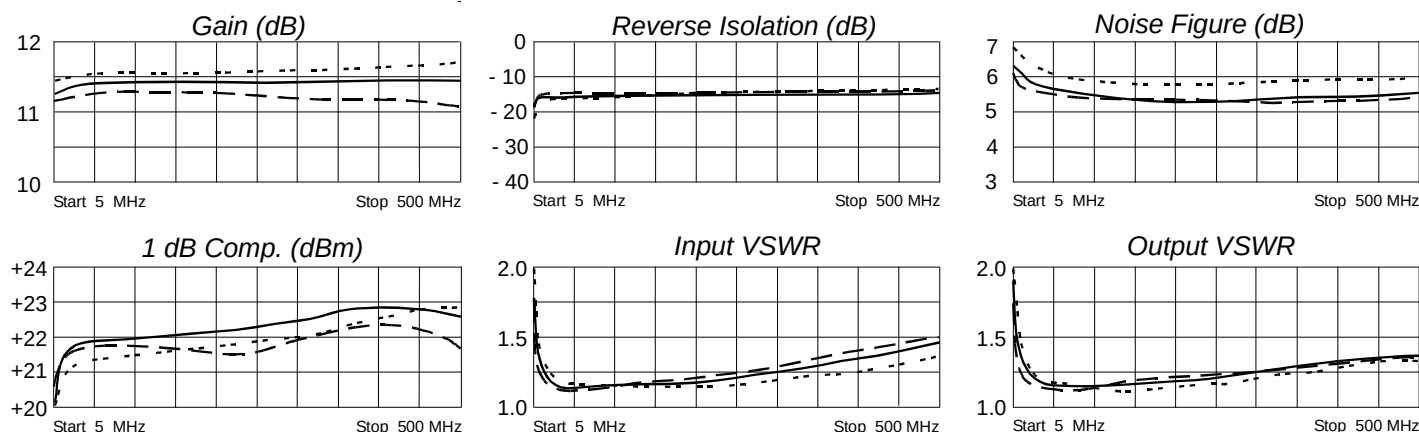
Second Order Harmonic Intercept Point.....+52 dBm (Typ.)
 Second Order Two Tone Intercept Point.....+46 dBm (Typ.)
 Third Order Two Tone Intercept Point.....+37 dBm (Typ.)

Maximum (No Damage) Ratings

Ambient Operating Temperature -55°C to + 100 °C
 Storage Temperature -62°C to + 125 °C
 Case Temperature + 125 °C
 DC Voltage + 17 Volts
 Continuous RF Input Power + 13 dBm
 Short Term RF Input Power 200 Milliwatts (1 Minute Max.)
 Maximum Peak Power 0.5 Watt (3 µsec Max.)

ECN 2-19-2024: Reduced Continuous RF Input from +20 dBm to +13 dBm

Typical Performance Data



Legend ——— + 25 °C - - - + 85 °C -55 °C

Linear S-Parameters

FREQ. MHz	S11		S21		S12		S22	
	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.31	- 51	3.70	-154	.12	32	.39	113
50	.05	-112	3.65	175	.16	2	.07	110
100	.06	-121	3.66	166	.16	-1	.07	102
200	.08	-121	3.66	149	.16	-2	.09	81
300	.11	-127	3.65	133	.17	-5	.11	71
400	.15	-134	3.67	117	.17	-8	.14	59
500	.19	-142	3.66	101	.17	-12	.16	49

